imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	80mΩ @ V _{GS} = 10V	4.1A
60V	100mΩ @ V _{GS} = 4.5V	3.6A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

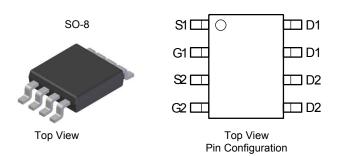
- Backlighting
- Power Management Functions
- DC-DC Converters

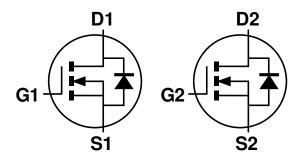
Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe Solderable per MIL-STD-202, Method 208
- Weight: 0.074 grams (Approximate)





Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN6070SSD-13	SO-8	2,500/Tape & Reel

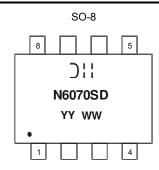
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



) | | = Manufacturer's Marking N6070SD = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 13 = 2013) WW = Week (01 - 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic Drain-Source Voltage Gate-Source Voltage			Symbol	Value	Units V	
			V _{DSS}	60		
			V _{GSS}	±20	V	
	Steady State	T _A = +25°C T _A = +70°C	ID	3.3 2.6	А	
Continuous Drain Current (Note 6) V _{GS} = 10V	t<10s	T _A = +25°C T _A = +70°C	Ι _D	4.1 3.4	А	
Maximum Continuous Body Diode Forward Current (Note 5)			Is	2.0	А	
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	12	A	
Avalanche Current (Note 7) L=0.1mH			I _{AS}	10	А	
Avalanche Energy (Note 7) L=0.1mH			E _{AS}	5.9	mJ	

Thermal Characteristics (@T_A= +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Total Power Dissipation (Note 5)		PD	1.2	W	
Thermal Desistance Junction to Ambient (Note E)	Steady State	D	104	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ extsf{ heta}JA}$	61	C/W	
Total Power Dissipation (Note 6)		PD	1.5	W	
Thermal Desistance, Junction to Ambient (Note 6)	Steady State		83	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	R _θ JA	50		
Thermal Resistance, Junction to Case	$R_{\theta JC}$	14.5			
Operating and Storage Temperature Range		TJ. TSTG	-55 to +150	°C	

Electrical Characteristics (@TA= +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Cymbol		- YP	max	Onit		
Drain-Source Breakdown Voltage	BV _{DSS}	60	—	_	V	I _D = 250μA, V _{GS} = 0V	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V _{DS} = 60V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	V _{GS} = ±16V, V _{DS} = 0V	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	1.0	_	3.0	V	I _D = 250μA, V _{DS} = V _{GS}	
Static Drain-Source On-Resistance			68	80	mΩ	V _{GS} = 10V, I _D = 4.5A	
Static Drain-Source On-Resistance	Rds (ON)	_	70	100		V _{GS} = 4.5V, I _D = 3.5A	
Diode Forward Voltage	V _{SD}	_	0.75	1.1	V	I _S = 12A, V _{GS} = 0V	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	_	588	_		V _{DS} = 30V, V _{GS} = 0V f= 1MHz	
Output Capacitance	C _{oss}	_	26.5		pF		
Reverse Transfer Capacitance	Crss	_	20	—			
Gate Resistance	R _g	_	1.5	_	Ω	Vgs= 0V, Vds= 0V, f=1MHz,	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	5.6	_			
Total Gate Charge (V _{GS} = 10V)	Qg	_	12.3	_	nC	V _{DS} = 30V, I _D = 3A	
Gate-Source Charge	Q _{gs}	_	1.7	_	nc		
Gate-Drain Charge	Q _{gd}	_	1.9	_			
Turn-On Delay Time	t _{D(on)}	_	3.5	_			
Turn-On Rise Time	tr	_	4.1	_	-0	$\label{eq:VDD} \begin{array}{l} V_{DD}\text{=} \; 30\text{V}, \; V_{GS}\text{=} \; 10\text{V} \\ R_L \cong 50\Omega, \; R_G \cong 20\Omega \end{array}$	
Turn-Off Delay Time	t _{D(off)}		35	_	nS		
Turn-Off Fall Time	t _f		11	_			
Body Diode Reverse Recovery Time	trr	_	18	_	nS	I _S = 12A, dI/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Qrr	_	12	_	nC	I _S = 12A, dl/dt = 100A/µs	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
7. I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep T_J = +25°C.
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing. Notes:



4.5 5

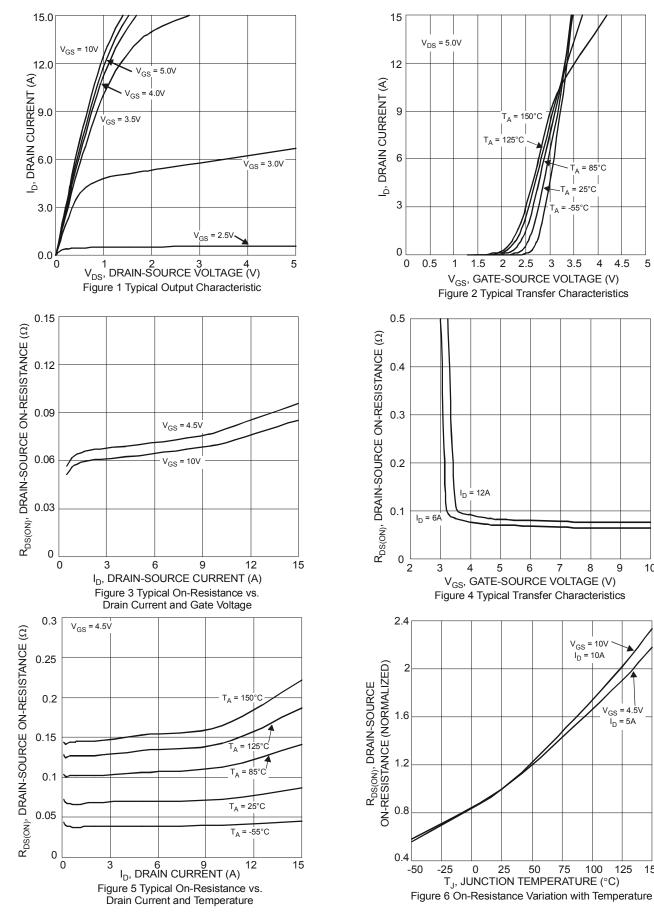
9

= 4.5V

= 5A

125

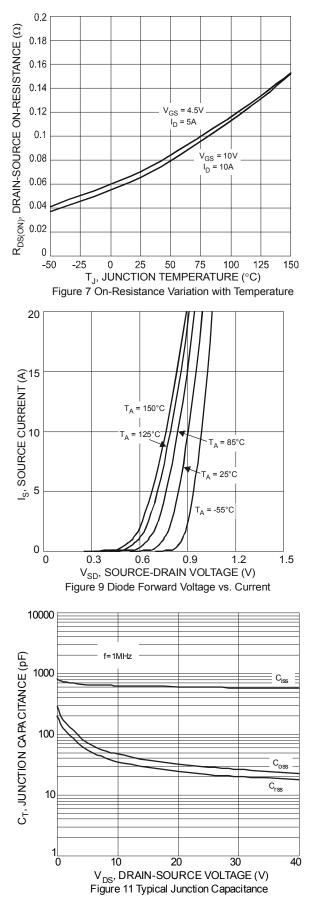
10

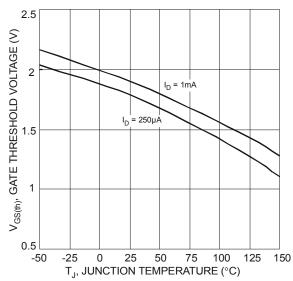


150

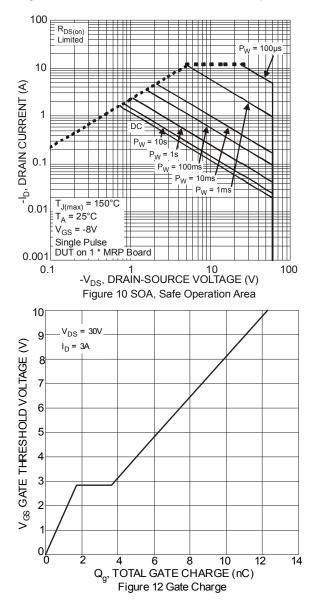




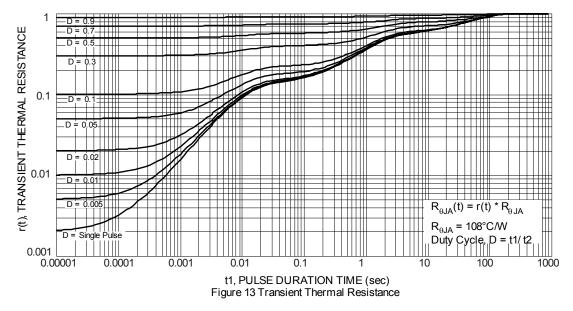






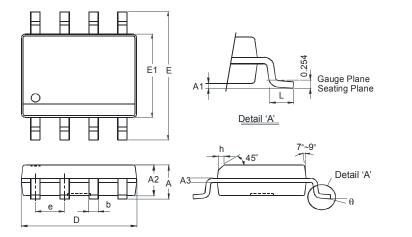






Package Outline Dimensions

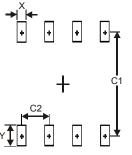
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SO-8					
Dim	Min	Max			
Α	-	1.75			
A1	0.10	0.20			
A2	1.30	1.50			
A3	0.15	0.25			
b	0.3	0.5			
D	4.85	4.95			
ш	5.90	6.10			
E1	3.85 3.95				
e	е 1.27 Тур				
h	- 0.35				
L	0.62	0.82			
θ	0°	8°			
All Di	All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

DMN6070SSD Document number: DS36342 Rev. 3 - 2



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com